



BUK7K12-60E

Dual N-channel 60 V, 9.3 mΩ standard level MOSFET

11 December 2013

Product data sheet

1. General description

Dual standard level N-channel MOSFET in an LFPAK56D (Dual Power-SO8) package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

2. Features and benefits

- Dual MOSFET
- Q101 compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True standard level gate with $V_{GS(th)}$ of greater than 1 V at 175 °C

3. Applications

- 12 V Automotive systems
- Motors, lamps and solenoid control
- Transmission control
- Ultra high performance power switching

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25 \text{ }^\circ\text{C}; T_j \leq 175 \text{ }^\circ\text{C}$		-	-	60	V
I_D	drain current	$V_{GS} = 10 \text{ V}; T_{mb} = 25 \text{ }^\circ\text{C}$; Fig. 1	[1]	-	-	40	A
P_{tot}	total power dissipation	$T_{mb} = 25 \text{ }^\circ\text{C}$; Fig. 2		-	-	68	W
Static characteristics FET1 and FET2							
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 10 \text{ A}; T_j = 25 \text{ }^\circ\text{C}$; Fig. 11		-	7.64	9.3	mΩ
Dynamic characteristics FET1 and FET2							
Q_{GD}	gate-drain charge	$I_D = 10 \text{ A}; V_{DS} = 48 \text{ V}; V_{GS} = 10 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; Fig. 13 ; Fig. 14		-	11	-	nC

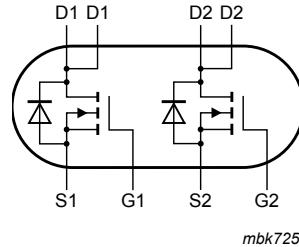
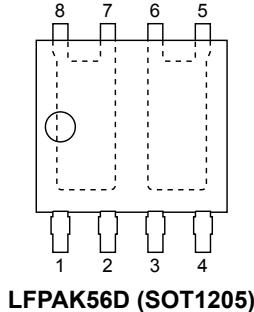
[1] Continuous current is limited by package.

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source1		
2	G1	gate1		
3	S2	source2		
4	G2	gate2		
5	D2	drain2		
6	D2	drain2		
7	D1	drain1		
8	D1	drain1		



6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BUK7K12-60E	LFPAK56D	Plastic single ended surface mounted package (LFPAK56D); 8 leads	SOT1205

7. Marking

Table 4. Marking codes

Type number	Marking code
BUK7K12-60E	71260E

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

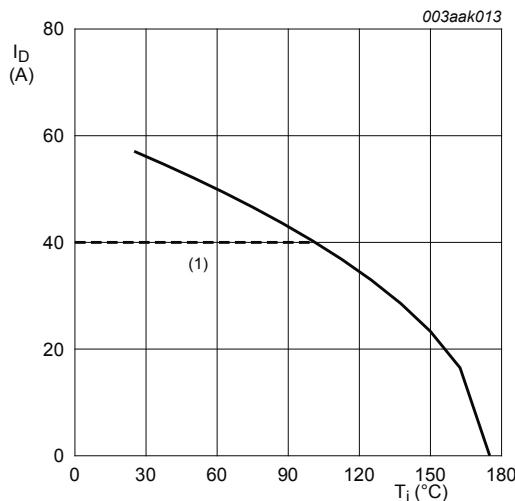
Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25^\circ\text{C}$; $T_j \leq 175^\circ\text{C}$		-	60	V
V_{DGR}	drain-gate voltage	$R_{GS} = 20\text{ k}\Omega$		-	60	V
V_{GS}	gate-source voltage	$T_j \leq 175^\circ\text{C}$; DC		-20	20	V
I_D	drain current	$V_{GS} = 10\text{ V}$; $T_{mb} = 25^\circ\text{C}$; Fig. 1	[1]	-	40	A
		$T_{mb} = 100^\circ\text{C}$; $V_{GS} = 10\text{ V}$; Fig. 1	[1]	-	40	A
I_{DM}	peak drain current	$T_{mb} = 25^\circ\text{C}$; pulsed; $t_p \leq 10\text{ }\mu\text{s}$; Fig. 4		-	228	A
P_{tot}	total power dissipation	$T_{mb} = 25^\circ\text{C}$; Fig. 2		-	68	W

Symbol	Parameter	Conditions	Min	Max	Unit
T _{stg}	storage temperature		-55	175	°C
T _j	junction temperature		-55	175	°C
Source-drain diode FET1 and FET2					
I _S	source current	T _{mb} = 25 °C	[1]	-	40 A
I _{SM}	peak source current	pulsed; t _p ≤ 10 µs; T _{mb} = 25 °C	-	228	A
Avalanche Ruggedness FET1 and FET2					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	I _D = 40 A; V _{sup} ≤ 60 V; V _{GS} = 10 V; T _{j(init)} = 25 °C; Fig. 3	[2][3]	-	103 mJ

[1] Continuous current is limited by package.

[2] Refer to application note AN10273 for further information

[3] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C



(1) Capped at 40A due to package

Fig. 1. Continuous drain current as a function of mounting base temperature

V_{GS} ≥ 10 V

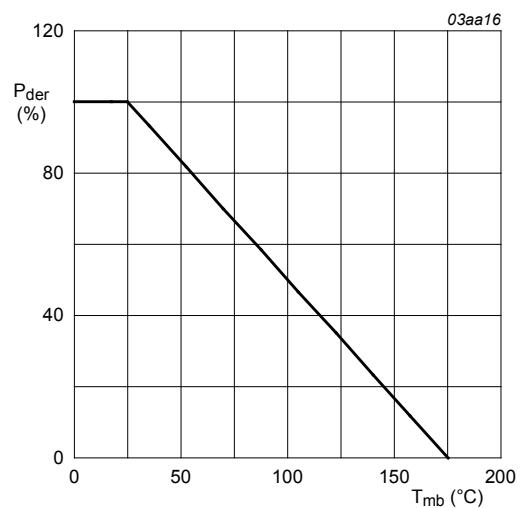


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot}(25^\circ\text{C})} \times 100 \%$$

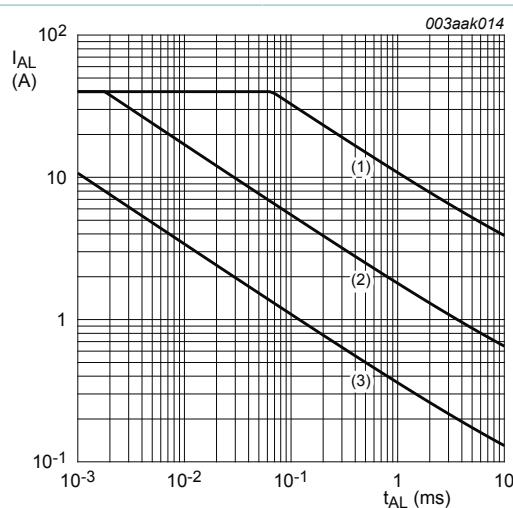


Fig. 3. Avalanche rating; avalanche current as a function of avalanche time

(1) $T_j (int) = 25^\circ C$; (2) $T_j (int) = 150^\circ C$; (3) Repetitive Avalanche

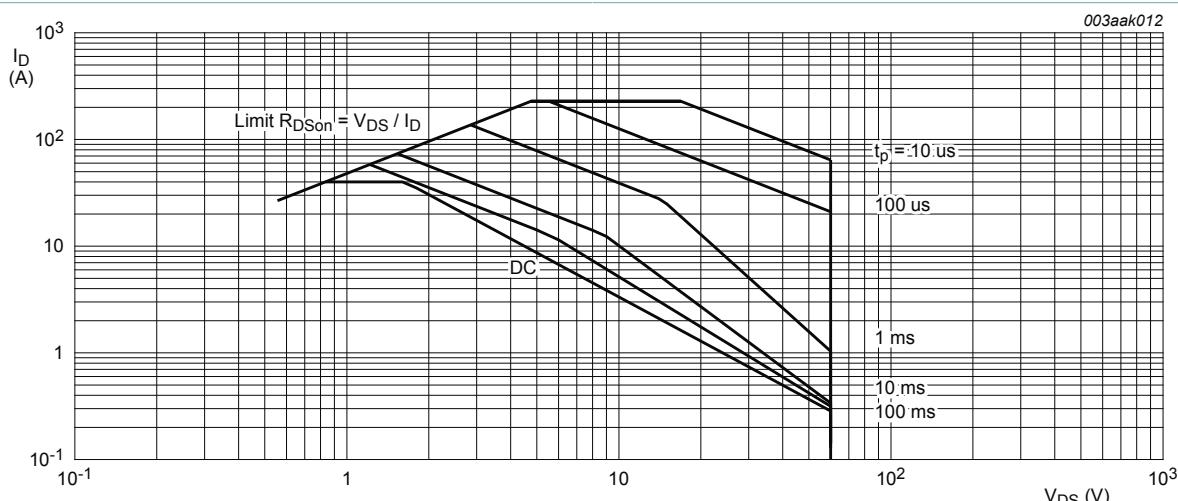


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25^\circ C$; I_{DM} is a single pulse

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5		-	-	2.21	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	Minimum footprint; mounted on a printed circuit board	-	95	-	-	K/W

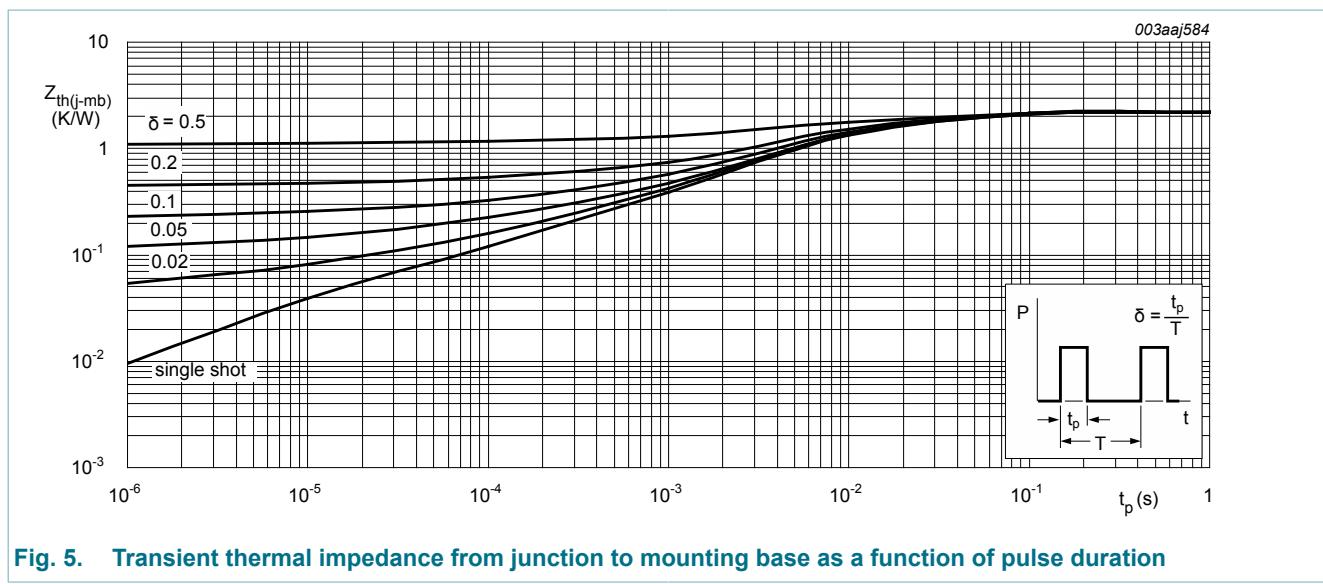


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics FET1 and FET2							
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55^\circ C$		54	-	-	V
		$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25^\circ C$		60	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25^\circ C$ Fig. 9 ; Fig. 10		2.4	3	4	V
		$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 175^\circ C$ Fig. 9 ; Fig. 10		1	-	-	V
		$I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55^\circ C$ Fig. 9 ; Fig. 10		-	-	4.5	V
I_{DSS}	drain leakage current	$V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25^\circ C$		-	0.02	1	μA
		$V_{DS} = 60 V; V_{GS} = 0 V; T_j = 175^\circ C$		-	-	500	μA
I_{GSS}	gate leakage current	$V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25^\circ C$		-	2	100	nA
		$V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25^\circ C$		-	2	100	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 V; I_D = 10 A; T_j = 25^\circ C$ Fig. 11		-	7.64	9.3	$m\Omega$
		$V_{GS} = 10 V; I_D = 10 A; T_j = 175^\circ C$ Fig. 11 ; Fig. 12		-	17.1	20.8	$m\Omega$
Dynamic characteristics FET1 and FET2							
$Q_{G(tot)}$	total gate charge	$I_D = 10 A; V_{DS} = 48 V; V_{GS} = 10 V; T_j = 25^\circ C$ Fig. 13 ; Fig. 14		-	34.2	-	nC
Q_{GS}	gate-source charge			-	6.7	-	nC
Q_{GD}	gate-drain charge			-	11	-	nC

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
C_{iss}	input capacitance	$V_{GS} = 0 \text{ V}$; $V_{DS} = 25 \text{ V}$; $f = 1 \text{ MHz}$; $T_j = 25 \text{ }^\circ\text{C}$; Fig. 15		-	1761	2348	pF
C_{oss}	output capacitance			-	247	297	pF
C_{rss}	reverse transfer capacitance			-	155	213	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 48 \text{ V}$; $R_L = 5 \Omega$; $V_{GS} = 10 \text{ V}$; $R_{G(ext)} = 5 \Omega$; $T_j = 25 \text{ }^\circ\text{C}$; $I_D = 10 \text{ A}$		-	9.1	-	ns
t_r	rise time			-	12.5	-	ns
$t_{d(off)}$	turn-off delay time			-	23	-	ns
t_f	fall time			-	15	-	ns

Source-drain diode FET1 and FET2

V_{SD}	source-drain voltage	$I_S = 10 \text{ A}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; Fig. 16		-	0.78	1.2	V
t_{rr}	reverse recovery time	$I_S = 10 \text{ A}$; $dI_S/dt = -100 \text{ A}/\mu\text{s}$; $V_{GS} = 0 \text{ V}$; $V_{DS} = 30 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$		-	25	-	ns
Q_r	recovered charge			-	24	-	nC

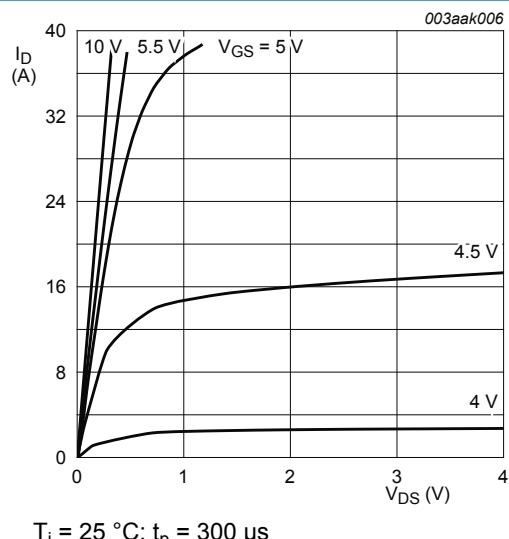


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

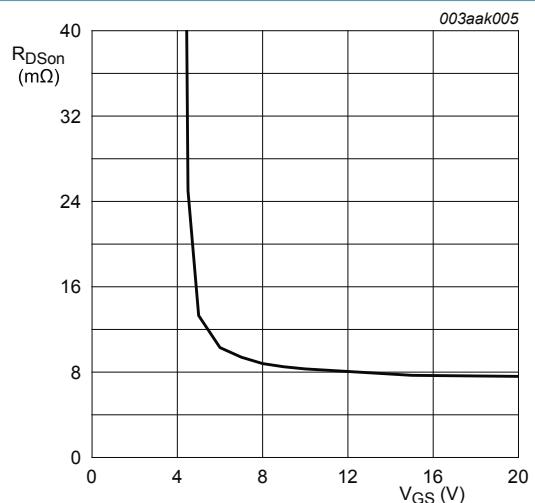


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25 \text{ }^\circ\text{C}$; $I_D = 10 \text{ A}$

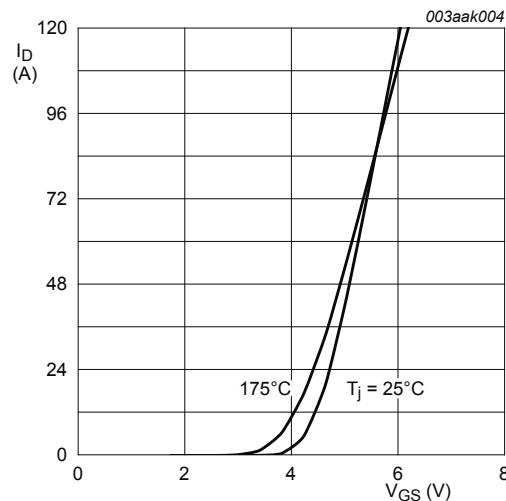


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$V_{DS} = 10\text{V}$

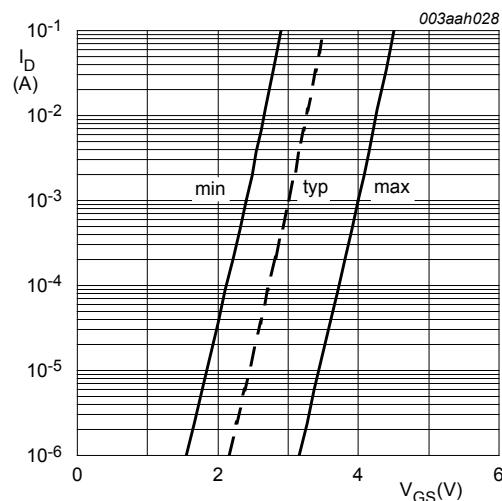


Fig. 9. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25^\circ\text{C}; V_{DS} = 5\text{V}$

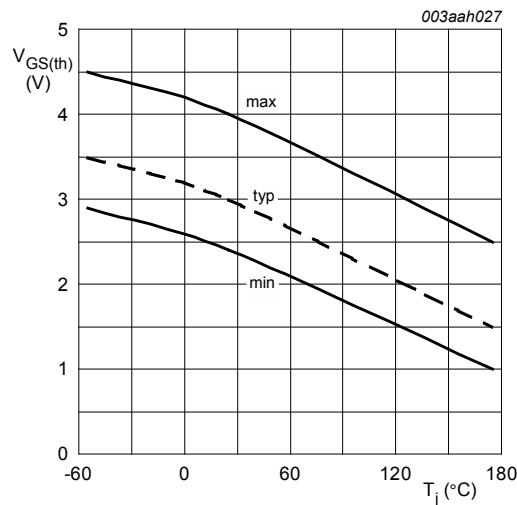


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$I_D = 1\text{ mA}; V_{DS} = V_{GS}$

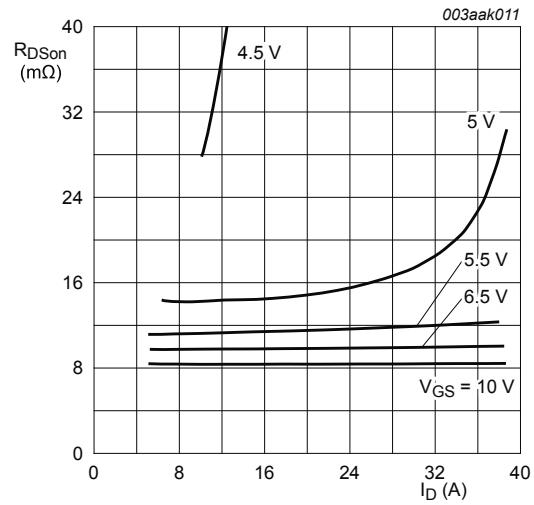


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

$T_j = 25^\circ\text{C}; t_p = 300\ \mu\text{s}$

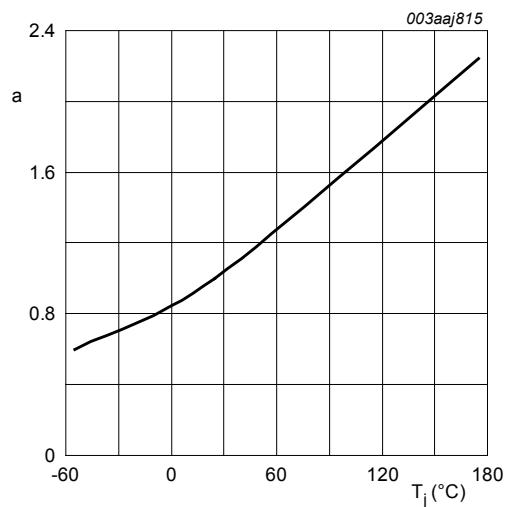


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon}(25^\circ\text{C})}$$

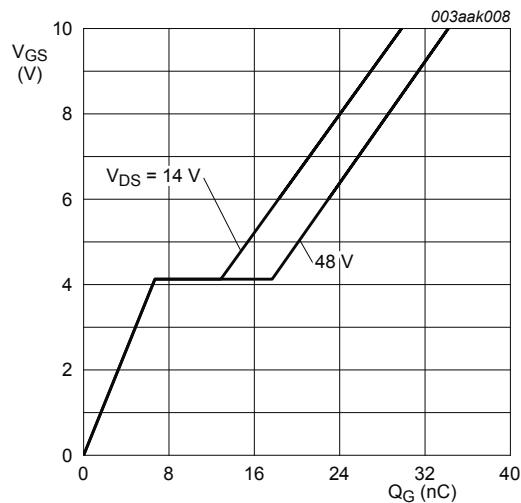


Fig. 14. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^\circ\text{C}; I_D = 10\text{A}$$

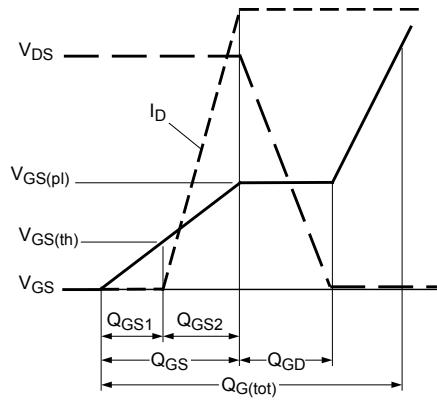


Fig. 13. Gate charge waveform definitions

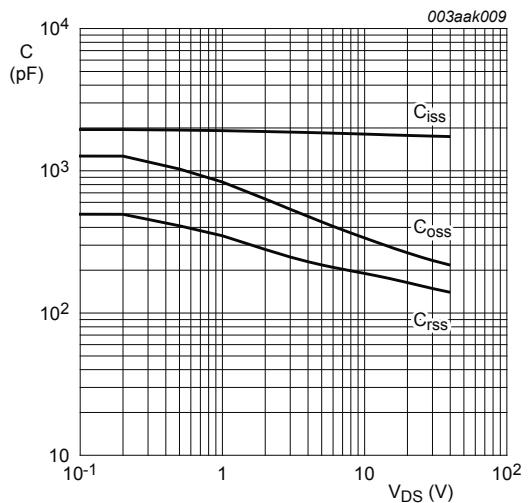


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = 0\text{V}; f = 1\text{MHz}$$

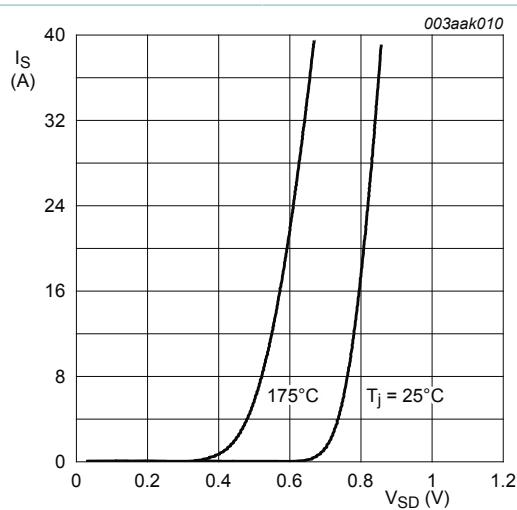


Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$$V_{GS} = 0 \text{ V}$$

11. Package outline

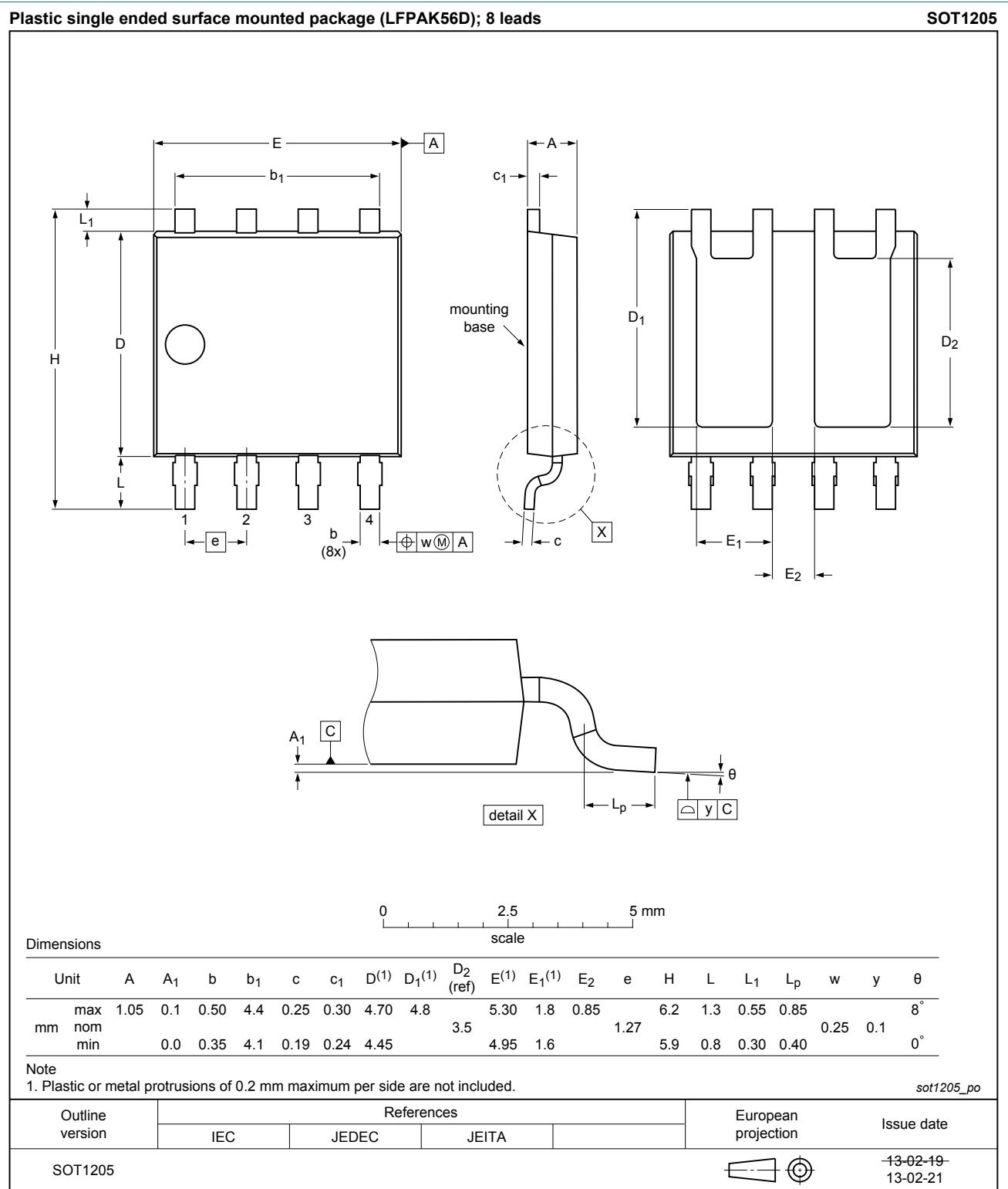


Fig. 17. Package outline LFPAK56D (SOT1205)

12. Legal information

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Document status [1][2]	Product status [3]	Definition
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Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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